

SPECIFICATION

Device Name	:	Power Integrated Module
Type Name	:	7MBR25UA120
Spec. No.	:	MS6M 0731

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Fuji Electric Co.,Ltd.
Matsumoto Factory

	DATE	NAME	APPROVED	Fuji Electric Co.,Ltd.			
DRAWN	Aug.-02-'03	Y.Kobayashi	T.Fujihira	DWG.NO.	MS6M 0731	1 / 15	a
CHECKED	Aug.-02-'03	T.Miyasaka					
		K.Yamada					

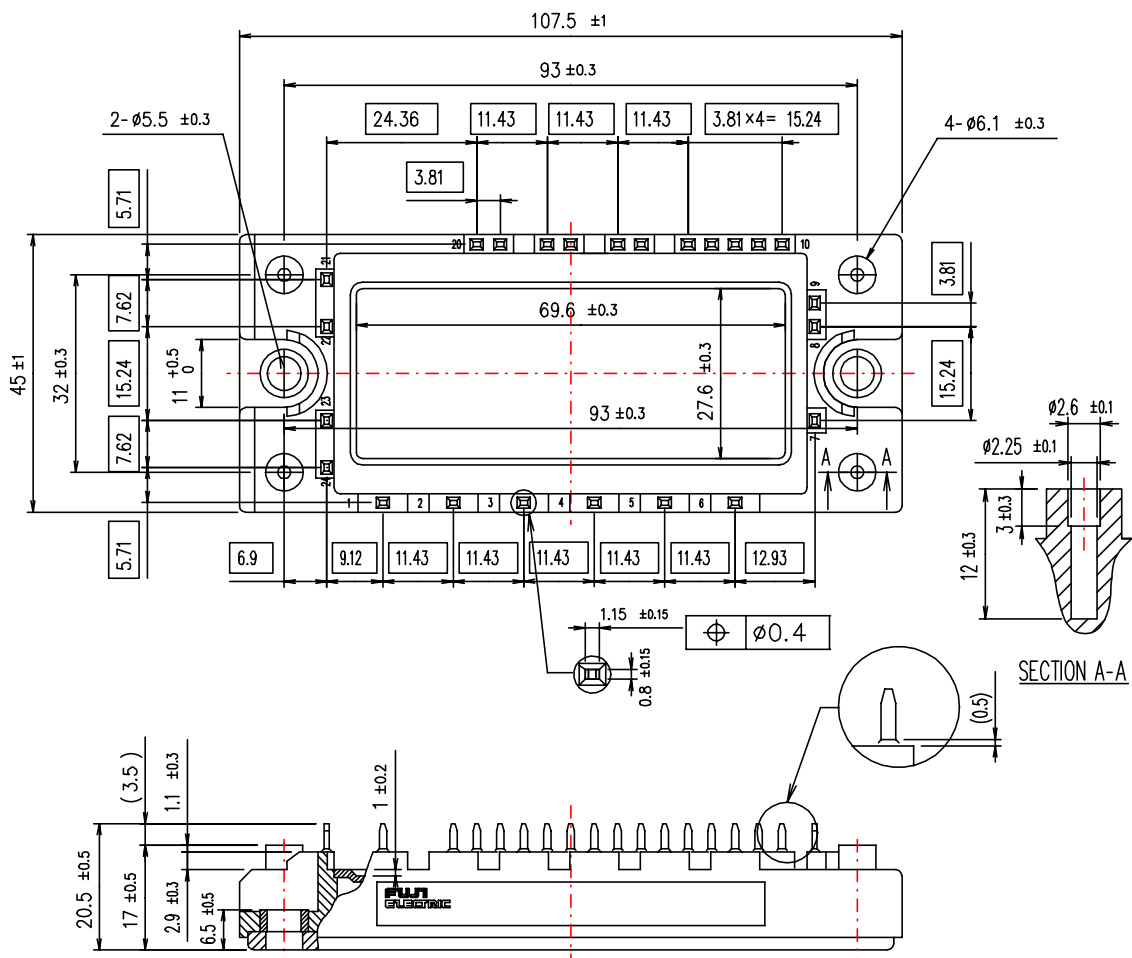
Revised Records

Date	Classi- fication	Ind.	Content	Applied date	Drawn	Checked	Approved
Aug.-02- '03	enactment	—	—	Issued date	—	T.Miyasaka K.Yamada	T.Fujihira
Dec.-17-'03	Revision	a	Revised VCE(sat)(P5/15) Revised sw-time (P5/15, 11/15) Revised trr,lrr (P12/15) Revised VF(P5/15, 12/15) Revised sw-loss (P11/15) Revised Warning (P14/15, 15/15)		Y.Kobayashi	T.Miyasaka K.Yamada	Y.Seki

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7MBR25UA120

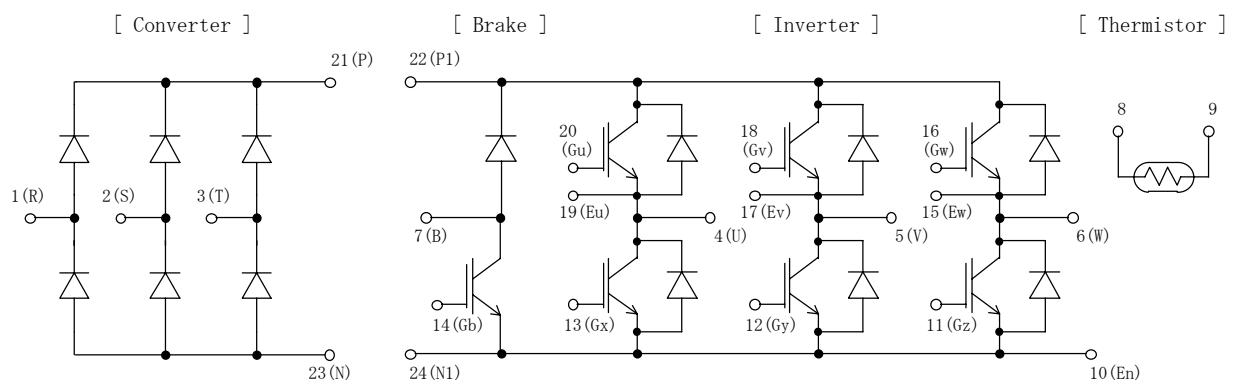
1. Outline Drawing (Unit : mm)



□ shows theoretical dimension.

() shows reference dimension.

2. Equivalent circuit



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H04-004-03

3. Absolute Maximum Ratings (at Tc= 25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum Ratings	Units	
Inverter	Collector-Emitter voltage	VCES			1200	V	
	Gate-Emitter voltage	VGES			±20	V	
	Collector current	Ic	Continuous	Tc=25°C	25	A	
				Tc=80°C	15		
		Icp	1ms	Tc=25°C	50		
				Tc=80°C	30		
		-Ic			25		
	-Ic pulse	1ms			50		
Collector Power Dissipation	Pc	1 device		115	W		
Brake	Collector-Emitter voltage	VCES			1200	V	
	Gate-Emitter voltage	VGES			±20	V	
	Collector current	Ic	Continuous	Tc=25°C	25	A	
				Tc=80°C	15		
		Icp	1ms	Tc=25°C	50		
				Tc=80°C	30		
	Collector Power Dissipation	Pc	1 device		115	W	
	Repetitive peak reverse Voltage (Diode)	VRRM			1200	V	
Repetitive peak reverse Voltage	VRRM			1600	V		
Converter	Average Output Current	Io	50Hz/60Hz sine wave		25	A	
	Surge Current (Non-Repetitive)	IFSM	Tj=150°C, 10ms half sine wave		260	A	
	I ² t (Non-Repetitive)	I ² t			338	A ² s	
	Junction temperature		Tj			150	°C
	Storage temperature		Tstg			-40 ~ +125	
Isolation voltage	between terminal and copper base *1	Viso	AC : 1min.		2500	VAC	
	between thermistor and others *2						
Screw Torque	Mounting *3	-			3.5	N m	

(*1) All terminals should be connected together when isolation test will be done.

(*2) Two thermistor terminals should be connected together, each other terminals should be connected together and shorted to base plate when isolation test will be done.

(*3) Recommendable Value : 2.5~3.5 Nm (M5)

4. Electrical characteristics (at Tj= 25°C unless otherwise specified)

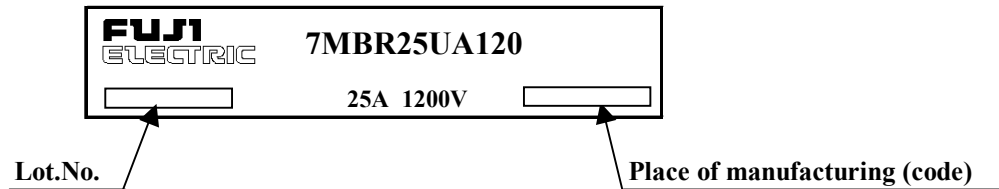
Items				Symbols	Conditions		Characteristics			Units
							min.	typ.	max.	
Inverter	Zero gate voltage Collector current		ICES	VGE = 0V VCE = 1200V		-	-	1.0	mA	
	Gate-Emitter leakage current		IGES	VCE = 0V VGE=±20V		-	-	200	nA	
	Gate-Emitter threshold voltage		VGE(th)	VCE = 20V Ic = 25mA		4.5	6.5	8.5	V	
	Collector-Emitter saturation voltage		VCE(sat) (terminal)	VGE=15V	Tj= 25°C	-	2.30	2.80	V	
					Tj=125°C	-	^a 2.75	-		
			VCE(sat) (chip)	Ic = 25A	Tj= 25°C	-	2.10	2.60		
					Tj=125°C	-	^a 2.55	-		
	Input capacitance		Cies	VCE=10V,VGE=0V,f=1MHz		-	2	-	nF	
	Turn-on time		ton	Vcc = 600V Ic = 25A VGE=±15V Rg = 68 Ω		-	^a 0.41	1.20	μ s	
			tr			-	^a 0.28	0.60		
			tr (i)			-	0.03	-		
	Turn-off time		toff			-	0.37	1.00		
			tf			-	0.07	0.30		
	Forward on voltage		VF (terminal)	VGE=0V	Tj= 25°C	-	^a 2.95	^a 3.55	V	
					Tj=125°C	-	^a 2.55	-		
VF (chip)			IF = 25A	Tj= 25°C	-	^a 2.75	^a 3.35			
				Tj=125°C	-	^a 2.35	-			
Reverse recovery time		trr	IF = 25A		-	-	0.35	μ s		
Brake	Zero gate voltage Collector current		ICES	VGE = 0V VCE = 1200V		-	-	1.0	mA	
	Gate-Emitter leakage current		IGES	VCE = 0V VGE=±20V		-	-	200	nA	
	Collector-Emitter saturation voltage		VCE(sat) (terminal)	VGE=15V	Tj= 25°C	-	2.30	2.80	V	
					Tj=125°C	-	^a 2.75	-		
			VCE(sat) (chip)	Ic = 25A	Tj= 25°C	-	2.10	2.60		
					Tj=125°C	-	^a 2.55	-		
	Turn-on time		ton	Vcc = 600V Ic = 25A		-	^a 0.41	1.20	μ s	
			tr			-	^a 0.28	0.60		
	Turn-off time		toff	VGE=±15V Rg = 68 Ω		-	0.37	1.00		
			tf			-	0.07	0.30		
Reverse current		IRRM	VR=1200V		-	-	1.0	mA		
Converter	Forward on voltage		VFM	VGE=0V IF = 25A	teminal chip	-	1.20 1.10	1.50 -	V	
	Reverse current		IRRM	VR=1600V		-	-	1.0	mA	
Thermistor	Resistance		R	T = 25°C T =100°C		- 465	5000 495	- 520	Ω	
	B value		B	T = 25/50°C		3305	3375	3450	K	

5. Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance(1device)	Rth(j-c)	Inverter IGBT	-	-	1.07	°C/W
		Inverter FWD	-	-	1.58	
		Brake IGBT	-	-	1.07	
		Converter Diode	-	-	0.90	
Contact Thermal resistance(1device)	Rth(c-f)	with Thermal Compound (*)	-	0.05	-	

* This is the value which is defined mounting on the additional cooling fin with thermal compound.

6. Indication on module



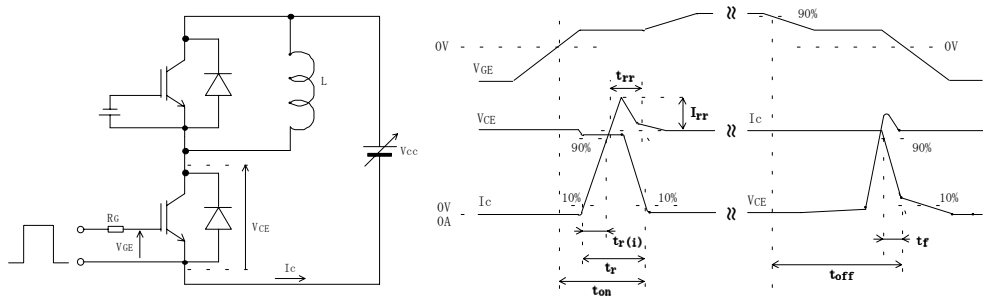
7. Applicable category

This specification is applied to IGBT Module named 7MBR25UA120 .

8. Storage and transportation notes

- The module should be stored at a standard temperature of 5 to 35°C and humidity of 45 to 75% .
- Store modules in a place with few temperature changes in order to avoid condensation on the module surface.
- Avoid exposure to corrosive gases and dust.
- Avoid excessive external force on the module.
- Store modules with unprocessed terminals.
- Do not drop or otherwise shock the modules when transporting.

9. Definitions of switching time



10. Packing and Labeling

Display on the packing box

- Logo of production
- Type name
- Lot No
- Products quantity in a packing box

11. Reliability test results

Reliability Test Items

Test categories	Test items	Test methods and conditions	Reference norms EIAJ ED-4701 (Aug.-2001 edition)	Number of sample	Acceptance number
Mechanical Tests	1 Terminal Strength (Pull test)	Pull force : 20N Test time : 10±1 sec.	Test Method 401 Method I	5	(0 : 1)
	2 Mounting Strength	Screw torque : 2.5 ~ 3.5 N·m (M5) Test time : 10±1 sec.	Test Method 402 method II	5	(0 : 1)
	3 Vibration	Range of frequency : 10 ~ 500Hz Sweeping time : 15 min. Acceleration : 100m/s ² Sweeping direction : Each X,Y,Z axis Test time : 6 hr. (2hr./direction)	Test Method 403 Reference 1 Condition code B	5	(0 : 1)
	4 Shock	Maximum acceleration : 5000m/s ² Pulse width : 1.0msec. Direction : Each X,Y,Z axis Test time : 3 times/direction	Test Method 404 Condition code B	5	(0 : 1)
	5 Solderability	Solder temp. : 235±5 °C Immersion time : 5±0.5sec. Test time : 1 time Each terminal should be Immersed in solder within 1~1.5mm from the body.	Test Method 303 Condition code A	5	(0 : 1)
	6 Resistance to Soldering Heat	Solder temp. : 260±5 °C Immersion time : 10±1sec. Test time : 1 time Each terminal should be Immersed in solder within 1~1.5mm from the body.	Test Method 302 Condition code A	5	(0 : 1)
Environment Tests	1 High Temperature Storage	Storage temp. : 125±5 °C Test duration : 1000hr.	Test Method 201	5	(0 : 1)
	2 Low Temperature Storage	Storage temp. : -40±5 °C Test duration : 1000hr.	Test Method 202	5	(0 : 1)
	3 Temperature Humidity Storage	Storage temp. : 85±2 °C Relative humidity : 85±5% Test duration : 1000hr.	Test Method 103 Test code C	5	(0 : 1)
	4 Unsaturated Pressure Cooker	Test temp. : 120±2 °C Atmospheric pressure : 1.7 × 10 ⁵ Pa Test humidity : 85±5% Test duration : 96hr.	Test Method 103 Test code E	5	(0 : 1)
	5 Temperature Cycle	Test temp. : Low temp. -40±5 °C High temp. 125 ±5 °C RT 5 ~ 35 °C Dwell time : High ~ RT ~ Low ~ RT 1hr. 0.5hr. 1hr. 0.5hr. Number of cycles : 100 cycles	Test Method 105	5	(0 : 1)
	6 Thermal Shock	Test temp. : High temp. 100⁺⁰₋₅ °C Low temp. 0⁺⁵₋₀ °C Used liquid : Water with ice and boiling water Dipping time : 5 min. par each temp. Transfer time : 10 sec. Number of cycles : 10 cycles	Test Method 307 method I Condition code A	5	(0 : 1)

Reliability Test Items

Test categories	Test items	Test methods and conditions	Reference norms EIAJ ED-4701 (Aug.-2001 edition)	Number of sample	Acceptance number
Endurance Tests	1 High temperature Reverse Bias	Test temp. : $T_a = 125 \pm 5 \text{ }^{\circ}\text{C}$ ($T_j \leq 150 \text{ }^{\circ}\text{C}$) Bias Voltage : $V_C = 0.8 \times V_{CES}$ Bias Method : Applied DC voltage to C-E $V_{GE} = 0\text{V}$ Test duration : 1000hr.	Test Method 101	5	(0 : 1)
	2 High temperature Bias (for gate)	Test temp. : $T_a = 125 \pm 5 \text{ }^{\circ}\text{C}$ ($T_j \leq 150 \text{ }^{\circ}\text{C}$) Bias Voltage : $V_C = V_{GE} = +20\text{V}$ or -20V Bias Method : Applied DC voltage to G-E $V_{CE} = 0\text{V}$ Test duration : 1000hr.	Test Method 101	5	(0 : 1)
	3 Temperature Humidity Bias	Test temp. : $85 \pm 2 \text{ }^{\circ}\text{C}$ Relative humidity : $85 \pm 5\%$ Bias Voltage : $V_C = 0.8 \times V_{CES}$ Bias Method : Applied DC voltage to C-E $V_{GE} = 0\text{V}$ Test duration : 1000hr.	Test Method 102 Condition code C	5	(0 : 1)
	4 Intermittent Operating Life (Power cycle) (for IGBT)	ON time : 2 sec. OFF time : 18 sec. Test temp. : $\Delta T_j = 100 \pm 5 \text{ deg}$ $T_j \leq 150 \text{ }^{\circ}\text{C}$, $T_a = 25 \pm 5 \text{ }^{\circ}\text{C}$ Number of cycles : 15000 cycles	Test Method 106	5	(0 : 1)

Failure Criteria

Item	Characteristic	Symbol	Failure criteria		Unit	Note
			Lower limit	Upper limit		
Electrical characteristic	Leakage current	ICES	-	USL×2	mA	
		±IGES	-	USL×2	μA	
	Gate threshold voltage	VGE(th)	LSL×0.8	USL×1.2	mA	
	Saturation voltage	VCE(sat)	-	USL×1.2	V	
	Forward voltage	VF	-	USL×1.2	V	
	Thermal resistance	IGBT or Δ VCE	-	USL×1.2	mV	
		FWD	Δ VF	USL×1.2	mV	
Visual inspection	Isolation voltage	Viso	Broken insulation		-	
	Visual inspection [Peeling Plating and the others	-	The visual sample		-	

LSL : Lower specified limit.

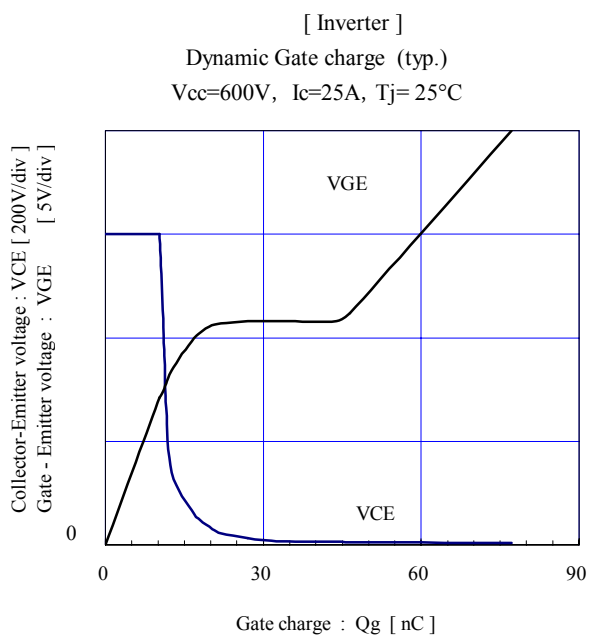
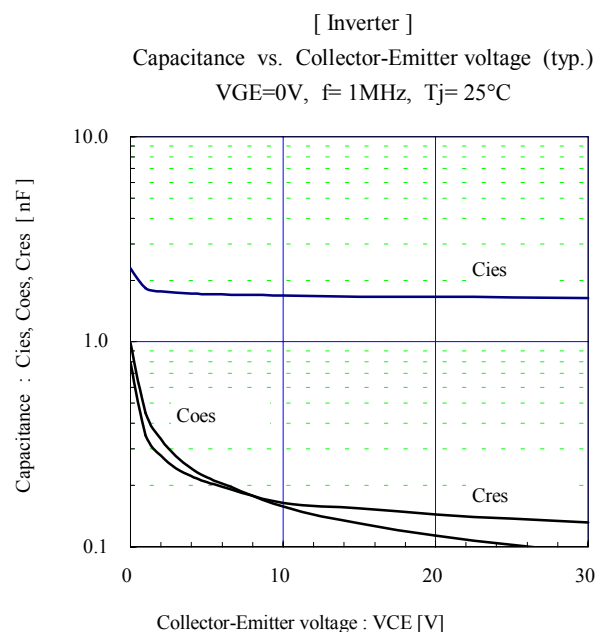
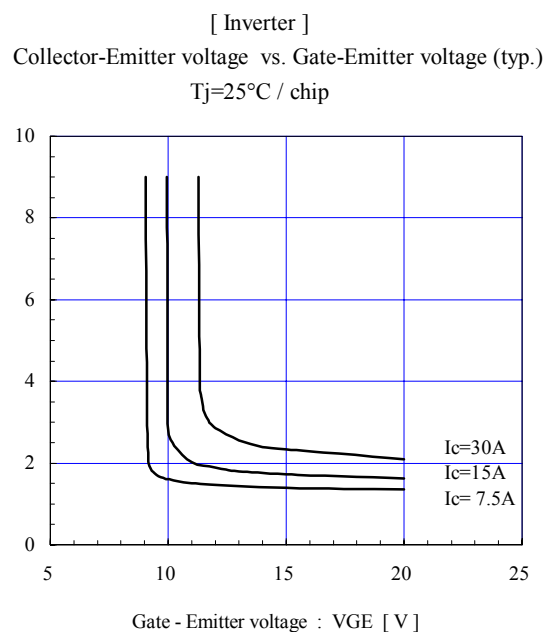
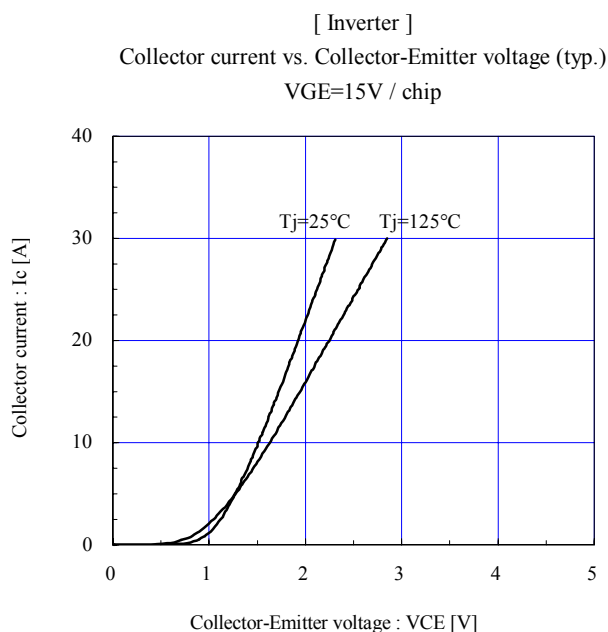
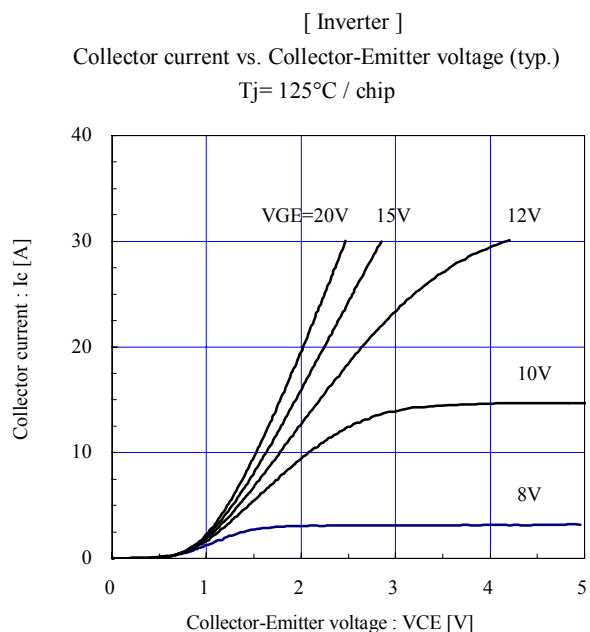
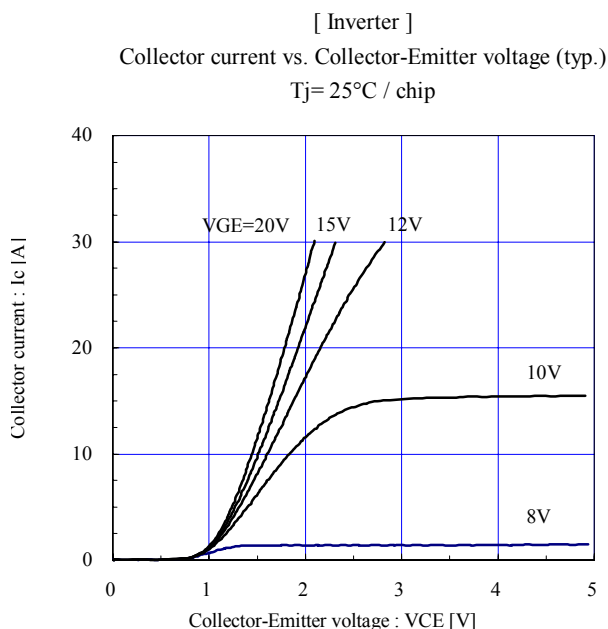
USL : Upper specified limit.

Note Each parameter measurement read-outs shall be made after stabilizing the components at room ambient for 2 hours minimum, 24 hours maximum after removal from the tests. And in case of the wetting tests, for example, moisture resistance tests, each component shall be made wipe or dry completely before the measurement.

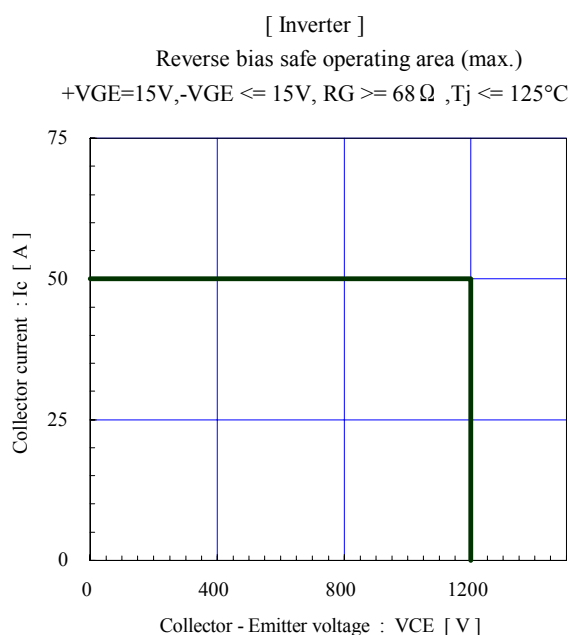
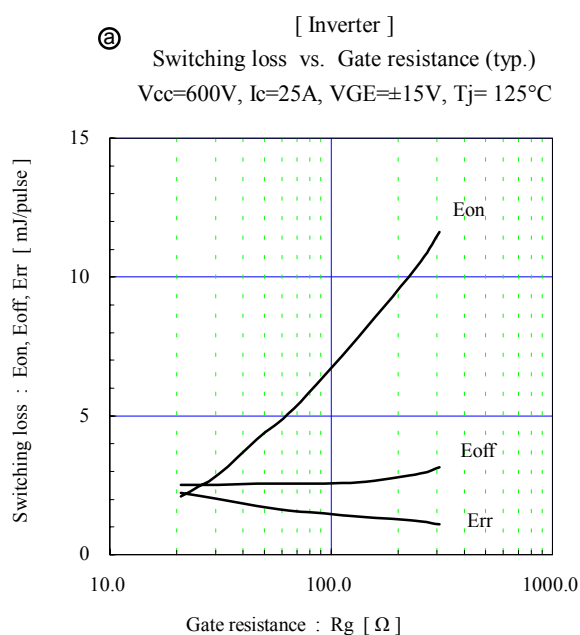
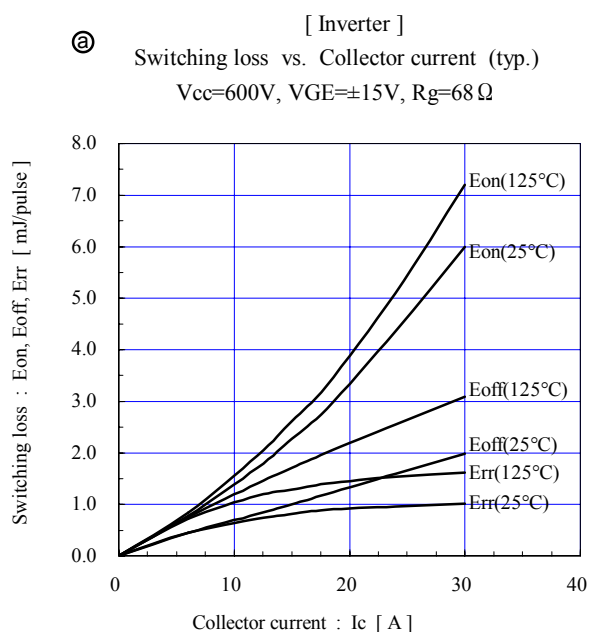
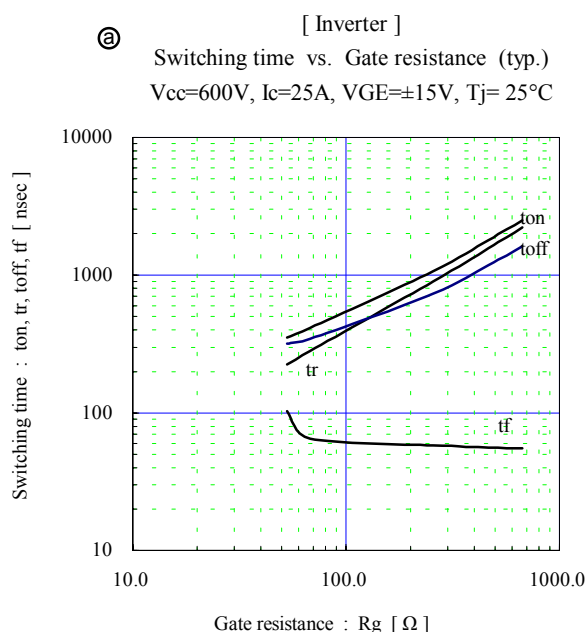
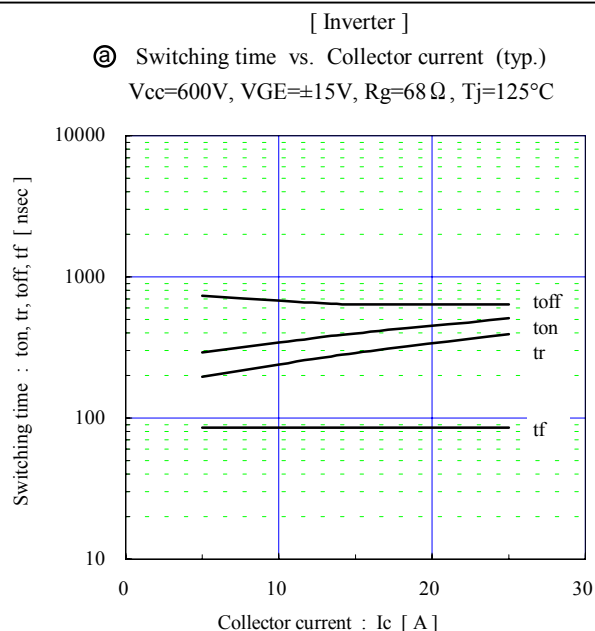
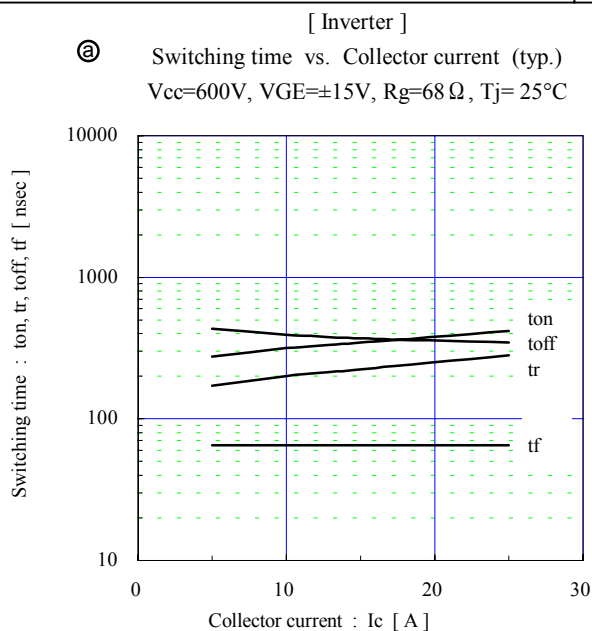
Reliability Test Results

Test categories	Test items	Reference norms EIAJ ED-4701 (Aug.-2001 edition)	Number of test sample	Number of failure sample
Mechanical Tests	1 Terminal Strength (Pull test)	Test Method 401 Method I	5	0
	2 Mounting Strength	Test Method 402 method II	5	0
	3 Vibration	Test Method 403 Condition code B	5	0
	4 Shock	Test Method 404 Condition code B	5	0
	5 Solderability	Test Method 303 Condition code A	5	0
	6 Resistance to Soldering Heat	Test Method 302 Condition code A	5	0
Environment Tests	1 High Temperature Storage	Test Method 201	5	0
	2 Low Temperature Storage	Test Method 202	5	0
	3 Temperature Humidity Storage	Test Method 103 Test code C	5	0
	4 Unsaturated Pressure Cooker	Test Method 103 Test code E	5	0
	5 Temperature Cycle	Test Method 105	5	0
	6 Thermal Shock	Test Method 307 method I Condition code A	5	0
Endurance Tests	1 High temperature Reverse Bias	Test Method 101	5	0
	2 High temperature Bias (for gate)	Test Method 101	5	0
	3 Temperature Humidity Bias	Test Method 102 Condition code C	5	0
	4 Intermitted Operating Life (Power cycling) (for IGBT)	Test Method 106	5	0

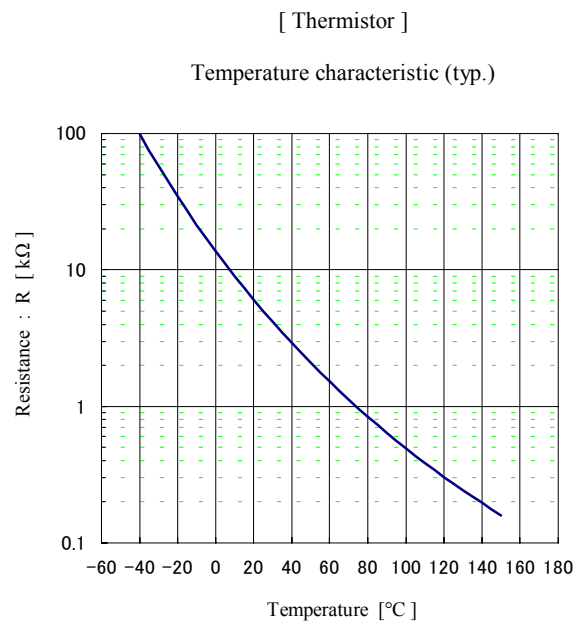
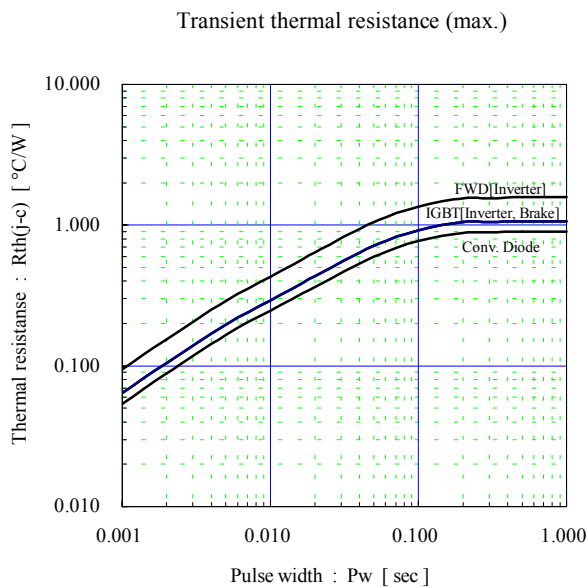
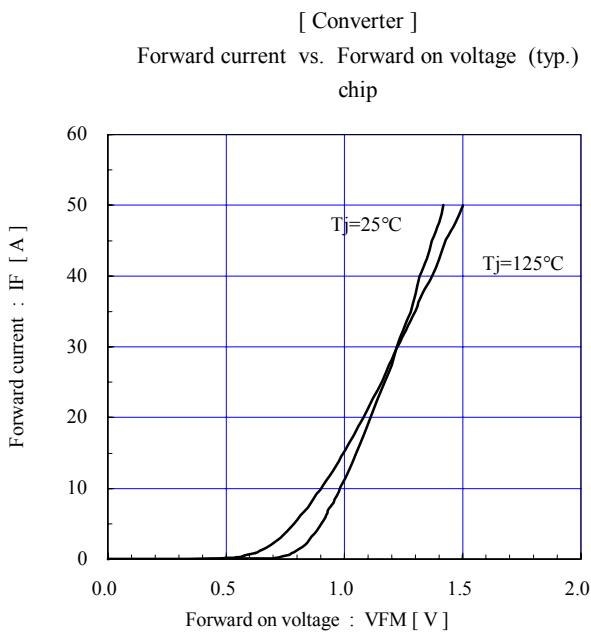
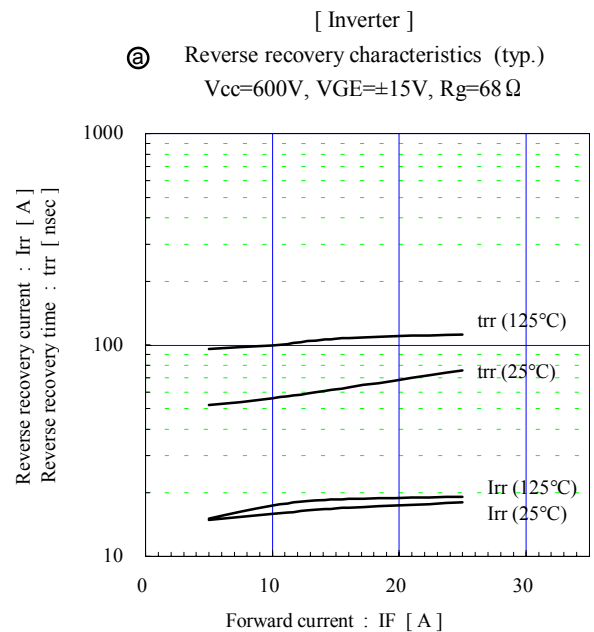
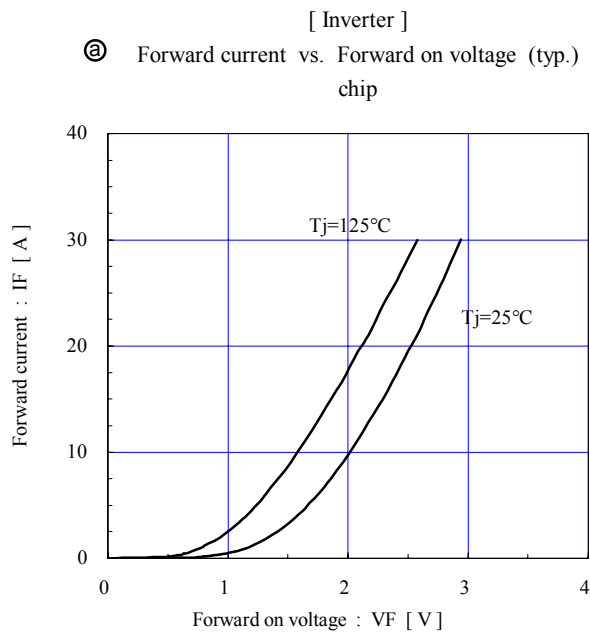
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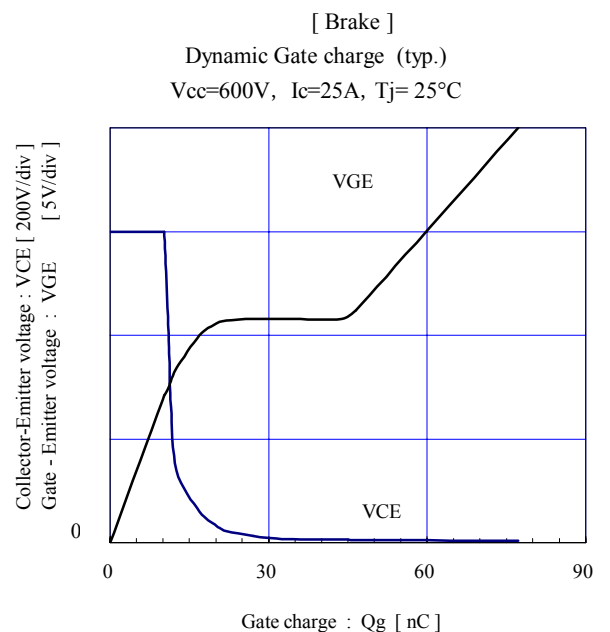
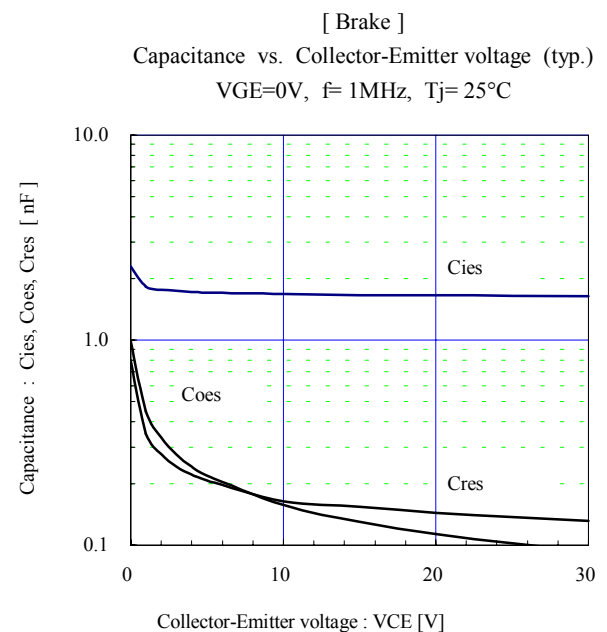
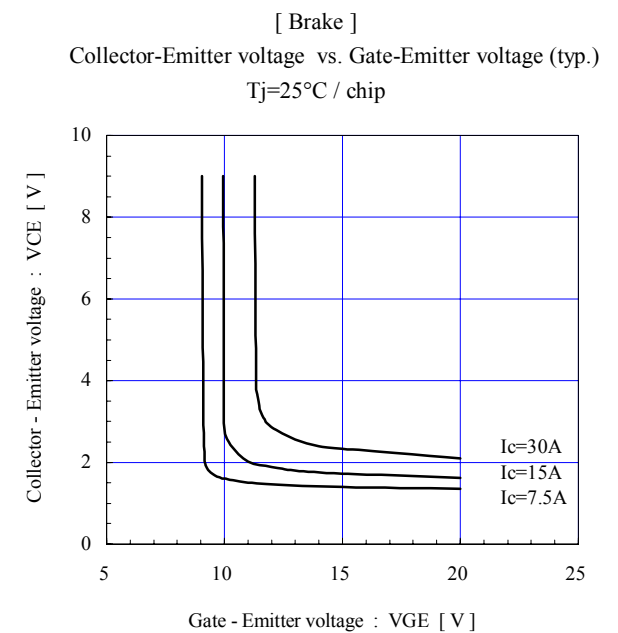
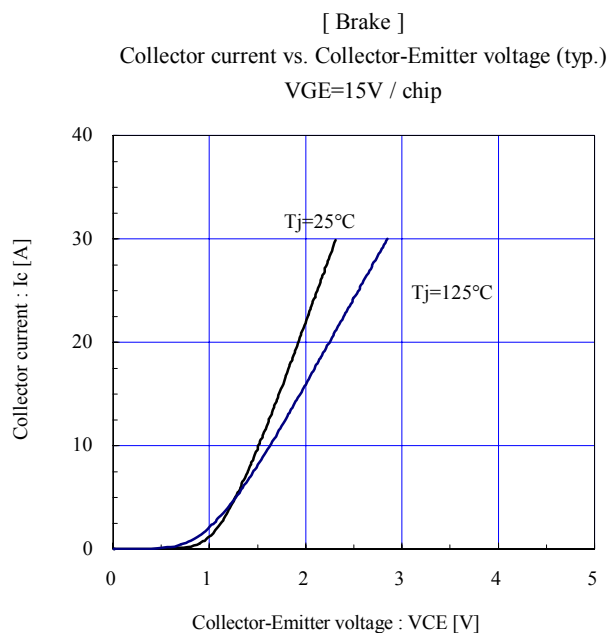
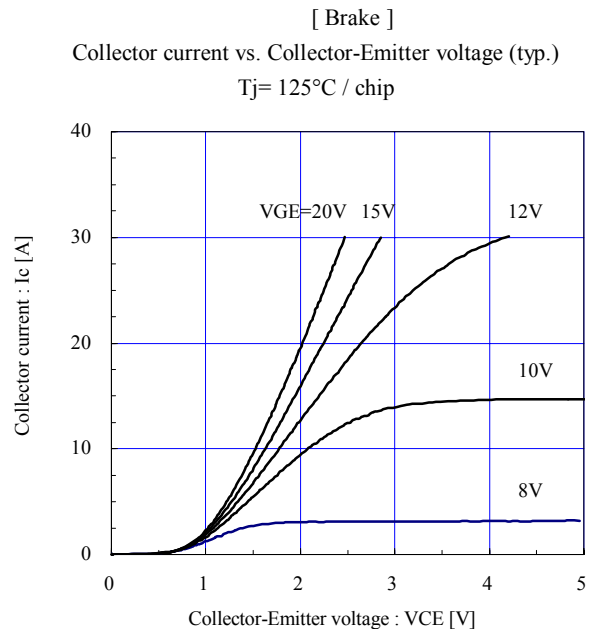
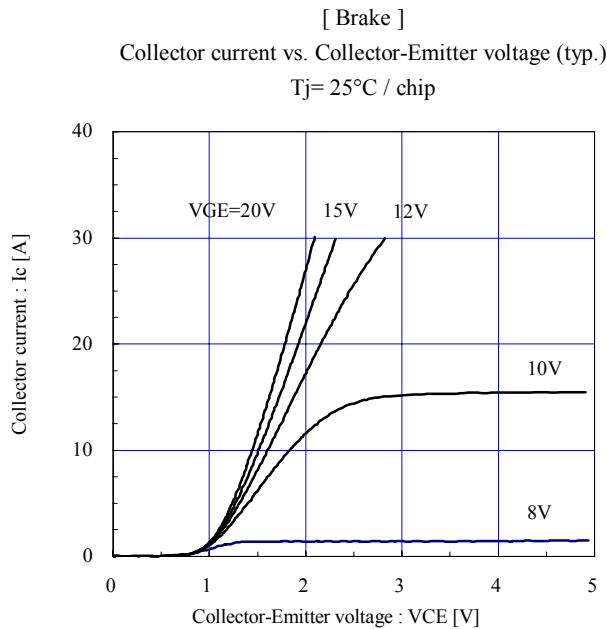
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Warnings

- This product shall be used within its absolute maximum rating (voltage, current, and temperature). This product may be broken in case of using beyond the ratings.
製品の絶対最大定格(電圧、電流、温度等)の範囲内で御使用下さい。絶対最大定格を超えて使用すると、素子が破壊する場合があります。
- Connect adequate fuse or protector of circuit between three-phase line and this product to prevent the equipment from causing secondary destruction, such as fire, its spreading, or explosion.
万一の不慮の事故で素子が破壊した場合を考慮し、商用電源と本製品の間に適切な容量のヒューズ又はブレーカーを必ず付けて火災、爆発、延焼等の2次破壊を防いでください。
- Use this product after realizing enough working on environment and considering of product's reliability life.
This product may be broken before target life of the system in case of using beyond the product's reliability life.
製品の使用環境を十分に把握し、製品の信頼性寿命が満足できるか検討の上、本製品を適用して下さい。製品の信頼性寿命を超えて使用した場合、装置の目標寿命より前に素子が破壊する場合があります。
- ^a- When electric power is connected to equipments, rush current will be flown through rectifying diode to charge DC capacitor. Guaranteed value of the rush current is specified as I^2t (non-repetitive), however frequent rush current through the diode might make it's power cycle destruction occur because of the repetitive power.
In application which has such frequent rush current, well consideration to product life time (i.e. suppressing the rush current) is necessary.
電源投入時に整流用ダイオードには、コンデンサーを充電する為の突入電流が流れます。この突入電流に対する保証値は I^2t (非繰返し)として表記されていますが、この突入電流が頻繁に流れると I^2t 破壊とは別に整流用ダイオードの繰返し負荷によるパワーサイクル耐量破壊を起こす可能性があります。突入電流が頻繁に流れるようなアプリケーションでは、突入電流値を抑えるなど、製品寿命に十分留意してご使用下さい。
- If the product had been used in the environment with acid, organic matter, and corrosive gas (hydrogen sulfide, sulfurous acid gas), the product's performance and appearance can not be ensured easily.
酸・有機物・腐食性ガス(硫化水素、亜硫酸ガス等)を含む環境下で使用された場合、製品機能・外観等の保証はできません。
- ^a- Use this product within the power cycle curve (Technical Rep.No. : MT5F12959). Power cycle capability is classified to delta-Tj mode which is stated as above and delta-Tc mode. Delta-Tc mode is due to rise and down of case temperature (Tc), and depends on cooling design of equipment which use this product. In application which has such frequent rise and down of Tc, well consideration of product life time is necessary.
本製品は、パワーサイクル寿命カーブ以下で使用下さい(技術資料No.: MT5F12959)。パワーサイクル耐量にはこの ΔTj による場合の他に、 ΔTc による場合があります。これはケース温度(Tc)の上昇・下降による熱ストレスであり、本製品をご使用する際の放熱設計に依存します。ケース温度の上昇・下降が頻繁に起こる場合は、製品寿命に十分留意してご使用下さい。
- Never add mechanical stress to deform the main or control terminal. The deformed terminal may cause poor contact problem.
主端子及び制御端子に応力を与えて変形させないで下さい。端子の変形により、接触不良などを引き起こす場合があります。
- ^a- Use this product with keeping the cooling fin's flatness between screw holes within 100um at 100mm and the roughness within 10um. Also keep the tightening torque within the limits of this specification. Too large convex of cooling fin may cause isolation breakdown and this may lead to a critical accident. On the other hand, too large concave of cooling fin makes gap between this product and the fin bigger, then, thermal conductivity will be worse and over heat destruction may occur.
冷却フィンにはネジ取り付け位置間で平坦度を100mmで100um以下、表面の粗さは10um以下にして下さい。過大な凸反りがあつたりすると本製品が絶縁破壊を起こし、重大事故に発展する場合があります。また、過大な凹反りやゆがみ等があると、本製品と冷却フィンの上に空隙が生じて放熱が悪くなり、熱破壊に繋がる場合があります。
- ^a- In case of mounting this product on cooling fin, use thermal compound to secure thermal conductivity. If the thermal compound amount was not enough or its applying method was not suitable, its spreading will not be enough, then, thermal conductivity will be worse and thermal run away destruction may occur.
Confirm spreading state of the thermal compound when its applying to this product.
(Spreading state of the thermal compound can be confirmed by removing this product after mounting.)
素子を冷却フィンに取り付ける際には、熱伝導を確保するためのコンパウンド等をご使用ください。又、塗布量が不足したり、塗布方法が不適当だったりすると、コンパウンドが十分に素子全体に広がらず、放熱悪化による熱破壊に繋がる事があります。コンパウンドを塗布する際には、製品全面にコンパウンドが広がっている事を確認してください。
(実装した後に素子を取りはずすとコンパウンドの広がり具合を確認する事が出来ます。)
- It shall be confirmed that IGBT's operating locus of the turn-off voltage and current are within the RBSOA specification. This product may be broken if the locus is out of the RBSOA.
ターンオフ電圧・電流の動作軌跡がRBSOA仕様内にあることを確認して下さい。RBSOAの範囲を超えて使用すると素子が破壊する可能性があります。
- If excessive static electricity is applied to the control terminals, the devices may be broken. Implement some countermeasures against static electricity.
制御端子に過大な静電気が印加された場合、素子が破壊する場合があります。取り扱い時は静電気対策を実施して下さい。
- Never add the excessive mechanical stress to the main or control terminals when the product is applied to equipments. The module structure may be broken.
素子を装置に実装する際に、主端子や制御端子に過大な応力を与えないで下さい。端子構造が破壊する可能性があります。

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Warnings

- In case of insufficient -VGE, erroneous turn-on of IGBT may occur. -VGE shall be set enough value to prevent this malfunction. (Recommended value : -VGE = -15V)
逆バイアスゲート電圧-VGEが不足しますと誤点弧を起こす可能性があります。誤点弧を起こさない為に-VGEは十分な値で設定して下さい。(推奨値 : -VGE = -15V)
- In case of higher turn-on dv/dt of IGBT, erroneous turn-on of opposite arm IGBT may occur. Use this product in the most suitable drive conditions, such as +VGE, -VGE, RG to prevent the malfunction.
ターンオン dv/dt が高いと対抗アームのIGBTが誤点弧を起こす可能性があります。誤点弧を起こさない為の最適なドライブ条件(+VGE, -VGE, RG等)でご使用下さい。
- This product may be broken by avalanche in case of VCE beyond maximum rating VCES is applied between C-E terminals. Use this product within its absolute maximum voltage.
VCESを超えた電圧が印加された場合、アバランシェを起こして素子破壊する場合があります。VCEは必ず絶対定格の範囲内でご使用下さい。

Cautions

- Fuji Electric Device Technology is constantly making every endeavor to improve the product quality and reliability. However, semiconductor products may rarely happen to fail or malfunction. To prevent accidents causing injury or death, damage to property like by fire, and other social damage resulted from a failure or malfunction of the Fuji Electric Device Technology semiconductor products, take some measures to keep safety such as redundant design, spread-fire-preventive design, and malfunction-protective design.
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- The product described in this specification is not designed nor made for being applied to the equipment or systems used under life-threatening situations. When you consider applying the product of this specification to particular used, such as vehicle-mounted units, shipboard equipment, aerospace equipment, medical devices, atomic control systems and submarine relaying equipment or systems, please apply after confirmation of this product to be satisfied about system construction and required reliability.
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